

NGTD17T65F2WP Information


For Reference Only

Part Number [NGTD17T65F2WP](#)
Manufacturer ON Semiconductor
Category Discrete Semiconductor Products
[Transistors - IGBTs - Single](#)
Description IGBT TRENCH FIELD STOP 650V DIE
Package Die
 For the pricing/inventory/lead time, please contact us
 Website: <https://www.heisener.com>
 E-mail: salesdept@heisener.com


[Request a Quote](#)
Certified Quality

Heisener's commitment to quality has shaped our processes for sourcing, testing, shipping, and every step in between. This foundation underlies each component we sell.


NGTD17T65F2WP Specifications

Manufacturer Part Number	NGTD17T65F2WP
Manufacturer	ON Semiconductor
Category	Discrete Semiconductor Products Transistors - IGBTs - Single
Package	Die
Series	-
IGBT Type	Trench Field Stop
Voltage - Collector Emitter Breakdown (Max)	650V
Current - Collector (Ic) (Max)	-
Current - Collector Pulsed (Icm)	160A
Vce(on) (Max) @ Vge, Ic	2V @ 15V, 40A
Power - Max	-
Switching Energy	-
Input Type	Standard
Gate Charge	-
Td (on/off) @ 25°C	-
Test Condition	-
Reverse Recovery Time (trr)	-
Operating Temperature	-55°C ~ 175°C (TJ)
Mounting Type	Surface Mount
Package / Case	Die
Supplier Device Package	Die

[Report errors?](#)

NGTD17T65F2WP Guarantees



Quality Guarantees

We provide 90 days warranty. *

If the items you received were not in perfect quality, we would be responsible for your refund or replacement, but the items must be returned in their original condition.



Service Guarantees

We guarantee 100% customer satisfaction.

Our experienced sales team and tech support team back our services to satisfy all our customers.

NGTD17T65F2WP Payment Methods



NGTD17T65F2WP Shipping Methods



If you have any question about NGTD17T65F2WP, please do not hesitate to contact us!

Website: <https://www.heisener.com>

E-mail: salesdept@heisener.com